

09/922,770

L Number	Hits	Search Text	DB	Time stamp
1	40	((438/7) or (438/116)).CCLS.) and @ad<19991212 and (gap or cavity) and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:37
2	917	((lithium adj niobate) near4 substrate) and @ad<19991212 and (semiconductor or electronic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:39
3	692	((lithium adj niobate) near4 substrate) and @ad<19991212 and (semiconductor or electronic)) and ((micro adj mechanical) or opto\$ or optical)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:40
4	688	((lithium adj niobate) near4 substrate) and @ad<19991212 and (semiconductor or electronic)) and ((micro adj mechanical) or optical or mems)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 16:14
5	4	((lithium adj niobate) near4 substrate) and @ad<19991212 and (semiconductor or electronic)) and ((micro adj mechanical) or optical or mems)) and ((cover or lid or cap) near4 transparent)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:50
6	82	((lithium adj niobate) near4 substrate) and @ad<19991212 and (semiconductor or electronic)) and ((micro adj mechanical) or optical or mems)) and (cavity or gap) and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:50
7	8090	(acoustic adj wave) and @ad<19991212 and (semiconductor or electronic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 16:18
8	298	((acoustic adj wave) and @ad<19991212 and (semiconductor or electronic)) and substrate and (gap or cavity) and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 16:19
-	40021	(MEMS or (micro adj mechanical) or opto or optical) and (gap or cavity) and (cap or lid or cover) and @ad<19991212	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:54
-	20874	((MEMS or (micro adj mechanical) or opto or optical) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and (semiconductor or electronic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:53
-	11083	((MEMS or (micro adj mechanical) or opto or optical) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and (semiconductor or electronic)) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:53
-	5297	((MEMS or (micro adj mechanical) or opto or optical) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and (semiconductor or electronic)) and substrate and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:54
-	1362	(MEMS or (micro adj mechanical)) and (gap or cavity) and (cap or lid or cover) and @ad<19991212	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:55

09/922,770

-	275	((MEMS or (micro adj mechanical)) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:56
-	193	((MEMS or (micro adj mechanical)) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and transparent) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 20:56
-	26	((MEMS or (micro adj mechanical)) and (gap or cavity) and (cap or lid or cover) and @ad<19991212) and transparent) and substrate) and lithium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 21:00
-	268	((438/7) or (438/116)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/22 21:01
-	40	((438/7) or (438/116)).CCLS.) and @ad<19991212 and (gap or cavity) and transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/08/23 15:30